

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of.:

Yair EIN-ELI et al

Serial No.:

10/750,969

Filed:

For:

January 5, 2004

TEXTURING A

SEMICONDUCTOR MATERIAL USING NEGATIVE POTENTIAL

DISSOLUTION (NPD)

Attorney Docket:

Group Art Unit:

27054

1742

Examiner:

Nicholas A. Smith

Mail Stop: Amendment Commissioner for Patents P.O. Box 1450

Alexandria, VA 22313-1450

Sir:

This is in response to the United States Patent and Trademark Restriction Office Action mailed February 2, 2007, which response is being made on or before March 2, 2007, and for which no extension of time fee is due.

Applicants hereby elect Group I, namely Claims 1-92, drawn to a method for texturing a semiconductor material.

Applicants reserve the right to file, at a later date, additional divisional applications claiming priority from the present application which are directed to the non-elected Group.

Respectfully submitted,

Martin D. Moynihan Registration No. 40,338

Date: March 1, 2007